Chapter 10

Transport Properties of Silicene Nanotube– and Silicene Nanoribbon–Based FETs

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ABSTRACT

Silicene is one of the most interesting nanomaterials. In this chapter, computational studies have been done on Silicene nanotube and nanoribbon-based FETs to analyze their transport properties. The FET is designed from armchair nanoribbon and single wall nanotube. The scattering region is capped by a dielectric and a metallic layer to form a gate. The conductance versus gate bias voltage, conductance versus temperature up to 2000K, and electrode temperature versus current characteristics are calculated and plotted along with the design of the equivalent model of the structure. Extended Hückel-based calculations were used, and the analysis shows the transport properties of both structures.
1.1 INTRODUCTION

Electrical and electronic devices initially comprised of two terminal devices, in which current flowed from one terminal to the other terminal. With development of technology three terminal devices were devised which we could control the flow of current between two terminals by the third terminal. Under category of three terminals devices, two models are widely accepted that is, Bipolar Function Transistor (BJT) and Field Effect Transistor (FET). FET is more widely used in Integrated circuits (ICs) as compare to BJT virtue its better electronic characteristics. The introduction of Field effect Transistors (FET) in the field of electronics has revolutionized the industry as the second revolution in electronics was introduced by the introduction of MOSFET’s in high speed desktops and hand held calculators.

A FET is a three-terminal device that uses electric field to control the flow of current. The three terminals are called source, gate and drain. Gate is applied with external voltage to control the current flowing from source to drain. FET is a unipolar device as it operates with the flow of only one type of charge carriers. As the field effect transistor the width of the channel along with the current can be varied with the external electrical field, hence FET is a voltage controlled device. FETs can N-type or P-type channel device.

A FET has three basic terminals. Source: the terminal from which the carrier enters (current denoted by $I_s$). Drain: the terminal from which the carrier leaves the channel (current denoted by $I_d$). Gate: the terminal that modulates the entire channel by applying voltage (current denoted by $I_g$) (sedra, 2003). All the terminals are attached with each other with ohmic contacts. FET can be classified into two types Metal-oxide semiconductor field effect transistor and junction field effect transistors. The basic working principle of a transistor is explained in figure 1.

Figure 1. Basic principle of a FET device
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